

Features

- · Trench MV MOSFET Technology
- · Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note1)
- · Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

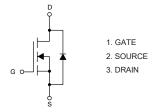
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Thermal Resistance: 833°C/W Junction to Ambient(Note2)

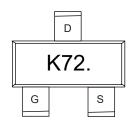
Parameter	Symbol	Rating	Unit		
Drain-Source Voltage	V _{DS}	60	V		
Gate-Source Volltage		V _{GS}	±20	V	
Continuous Drain Current	T _A =25°C	- I _D	115		
	T _A =100°C		73	mA	
Pulsed Drain Current ^(Note 3)		I _{DM}	460	mA	
Total Power Dissipation (Note 4)		P _D	150	mW	

Note:

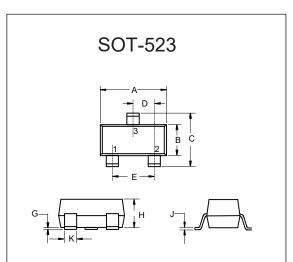
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of $R_{\theta JA}$ is measured with the device mounted on the minimum recommended pad size, in a still air environment with T_A =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

Internal Structure and Marking Code



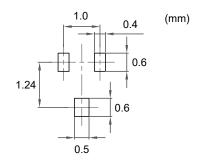


N-Channel MOSFET



	DIMENSIONS					
DIM	INCHES		MM		NOTE	
DIIVI	MIN	MAX	MIN	MAX	NOTE	
Α	0.059	0.067	1.50	1.70		
В	0.030	0.033	0.75	0.85		
С	0.057	0.069	1.45	1.75		
D	0.020		0.50		TYP.	
Е	0.035	0.043	0.90	1.10		
G	0.000	0.004	0.00	0.10		
Н	0.024	0.031	0.60	0.80		
J	0.004	0.008	0.10	0.20		
K	0.006	0.014	0.15	0.35		

Suggested Solder Pad Layout





Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
Static Characteristics					I		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =10μA	60			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=250\mu A$	1.0	1.5	2.0	V	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V			±10	μA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1	μA	
Drain-Source On-Resistance	В	V _{GS} =10V, I _D =500mA		2.2 5			
	R _{DS(on)}	V _{GS} =4.5V, I _D =50mA		2.0	7.5	Ω	
Forward Transconductance	g _{FS}	V _{DS} =5V, I _D =300mA		300		mS	
Gate Resistance	R _g	f=1 MHz, Open drain		130		Ω	
Diode Characteristics					I.	1	
Continuous Body Diode Current	Is				115	mA	
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =115mA			1.3	V	
Reverse Recovery Time	t _{rr}	I _F =300mA, dI _F /dt=100A/μs		11		ns	
Reverse Recovery Charge	Q _{rr}	1 15-300111A, 015/01-100A/µS		2.6		nC	
Dynamic Characteristics							
Input Capacitance	C _{iss}			15.6			
Output Capacitance	C _{oss}	V _{DS} =25V,V _{GS} =0V,f=1MHz		3		pF	
Reverse Transfer Capacitance	C _{rss}			2			
Total Gate Charge	Q _g			0.88			
Gate-Source Charge	Q _{gs}	V _{DS} =30V,V _{GS} =10V,I _D =300mA		0.15		nC	
Gate-Drain Charge	Q_{gd}			0.25			
Turn-On Delay Time	t _{d(on)}			3			
Turn-On Rise Time	t _r	V _{DD} =30V,V _{GS} =10V,		4			
Turn-Off Delay Time	t _{d(off)}	$R_G=50\Omega$, $R_L=250\Omega$		11		- ns	
Turn-Off Fall Time	t _f			31			



Curve Characteristics

Fig.1 - Typical Output Characteristics

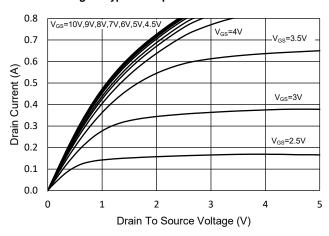


Fig.2 - Transfer Characteristic

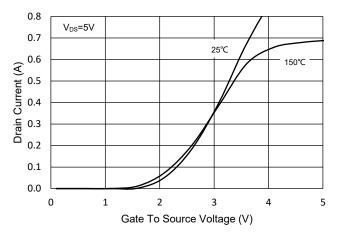


Fig.3 - R_{DS(ON)} - V_{GS}

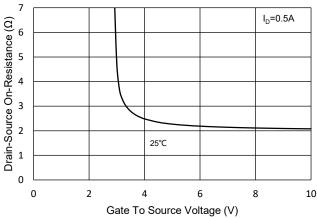


Fig.4 - R_{DS(ON)} - I_D

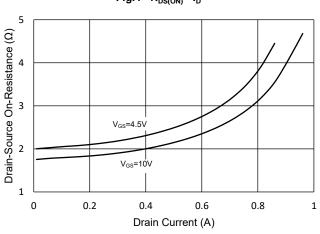


Fig.5 - Capacitance Characteristics

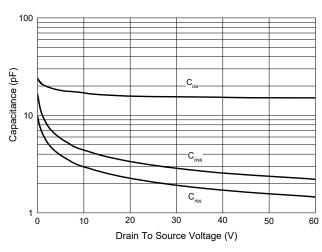
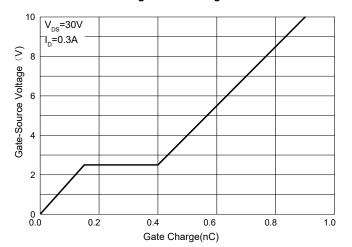
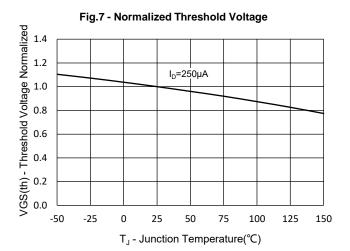


Fig.6 - Gate Charge





Curve Characteristics



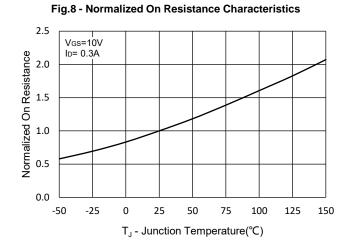
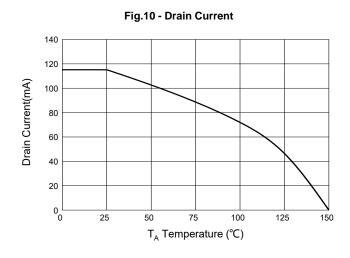
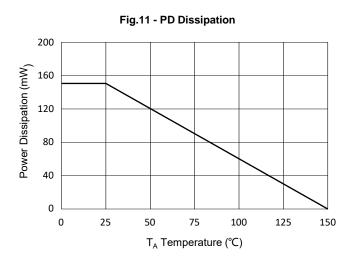


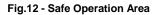
Fig.9 - I_S - V_{SD} 2 V_{GS}=0V Source Current (A) 150℃ 25℃ 0.1 0.0 0.2 0.4 0.6 8.0 1.0 1.2 1.4 Source To Drain Voltage (V)







Curve Characteristics



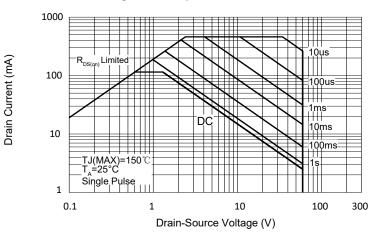
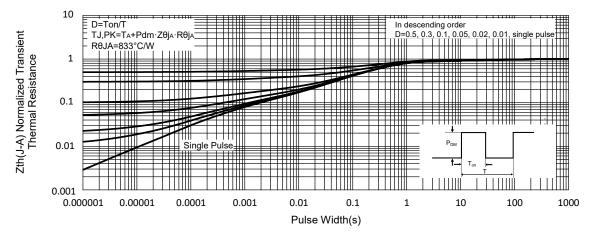


Fig.13 - Normalized Transient Thermal Impedance





Ordering Information

Device	Packing	
Part Number-TP	Tape&Reel:3Kpcs/Reel	

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